

GaAs SPDT Switch DC - 6.0 GHz

Rev. V6

Features

- Low Insertion Loss: 0.5 dB Typical @ 4 GHz
- Fast Switching Speed: 4 ns Typical
- Ultra Low DC Power Consumption

Description

M/A-COM Technology's MASW6010G is an SPDT GaAs MESFET MMIC. This part combines small size, low insertion loss and power consumption with high isolation. Ideal for many applications and module use. It will function well for designs below 6 GHz.

This die includes full passivation for performance and reliability.

Ordering Information¹

Part Number	Package
MASW6010G	Die

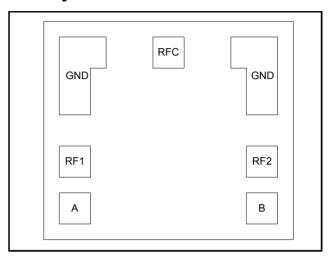
1. Die quantity varies.

Absolute Maximum Ratings ²

Parameter	Absolute Maximum		
Control Voltage (A/B)	-8.5 VDC		
Input RF Power	+34 dBm (500 MHz - 6 GHz)		
Operating Temperature	+175°C		
Storage Temperature	-65°C to +175°C		

Exceeding any one or combination of these limits may cause permanent damage to this device.

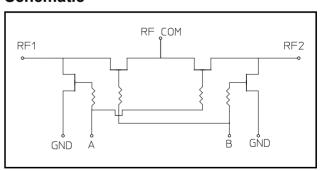
Pad Layout



Bond Pad Dimensions

Bond Pad	Dimension Inches (mm)		
RFC	0.004 x 0.004 (0.100 x 0.100)		
RF2, RF3	0.004 x 0.004 (0.100 x 0.100)		
A, B	0.004 x 0.004 (0.100 x 0.100)		
GND1, GND2	0.012 x 0.004 (0.300 x 0.100)		
DIE Size	0.031 x 0.031 x 0.010 (0.80 x 0.80 x 0.25)		

Schematic





GaAs SPDT Switch DC - 6.0 GHz

Rev. V6

Electrical Specifications 3,4 : $T_A = 25^{\circ}C$, $Z_0 = 50 \Omega$

Parameter	Test Conditions		Min.	Тур.	Max.
Insertion Loss	DC - 1.0 GHz DC - 2.0 GHz DC - 6.0 GHz				0.6 0.8 1.4
Isolation	DC - 1.0 GHz DC - 2.0 GHz DC - 6.0 GHz		45 38 22		
VSWR	DC - 1.0 GHz DC - 2.0 GHz Ratio DC - 6.0 GHz		_ _ _	_ _ _	1.1:1 1.2:1 1.9:1
Trise, Tfall	10% to 90% RF and 90% to 10% RF ns		_	2	_
Ton, Toff	50% control to 90% RF, and 50% control to 10% RF		_	4	_
Transients	In-Band	mV	_	10	_
Input P1dB	Above 500 MHz, 0 to -5 V 100 MHz, 0 to -5 V Above 500 MHz, 0 to -8 V 100 MHz, 0 to -8 V		_ _ _ _	+27 +21 +33 +26	 - -
IP2	Two Tone, +5 dBm/Tone, 5 MHz Spacing Above 500 MHz 100 MHz dBm			+68 +62	
IIP3	Two Tone, +5 dBm/Tone, 5 MHz Spacing Above 500 MHz 100 MHz	dBm		+46 +40	_
Control Voltage (Complementary Logic)	V _{IN} Low, 0 to -0.2 V V _{IN} High, -5 V V _{IN} High, -8 V	μА			20 50 300

^{3.} All specifications apply with 50-ohm impedance connected to all RF ports, 0 and -8 VDC control voltages.

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Truth Table ⁵

Control	Control Inputs Condition of Switch RF Common to each RF F		
Α	В	RF1	RF2
V _{IN} Hi	V _{IN} Low	On	Off
V _{IN} Low	V _{IN} Hi	Off	On

^{5.} V_{IN} Low = 0 to -0.2 V, V_{IN} High = -5 to -8 V.

^{4.} Loss changes 0.0025 dB/°C (From -55°C to +85°C).

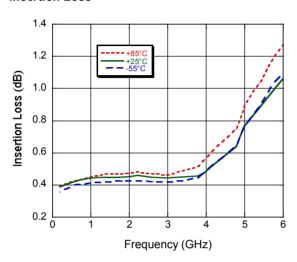


GaAs SPDT Switch DC - 6.0 GHz

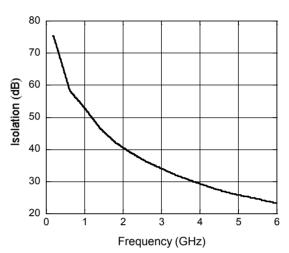
Rev. V6

Typical Performance Curves

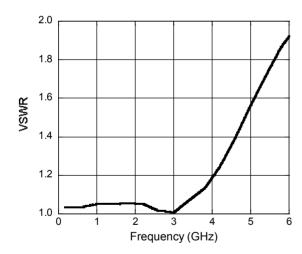
Insertion Loss



Isolation



VSWR





GaAs SPDT Switch DC - 6.0 GHz

Rev. V6

Handling Procedures

Permanent damage to the MASW6010G may occur if the following precautions are not adhered to:

- A. Cleanliness The MASW6010G should be handled in a clean environment. DO NOT attempt to clean assembly after the MASW6010G is installed.
- B. Static Sensitivity All die handling equipment and personnel should be DC grounded.
- C. Transients Avoid instrument and power supply transients while bias is connected to the MASW6010G. Use shielded signal and bias cables to minimize inductive pick-up.
- D. Bias Apply voltage to either control port A/B or only when the other is grounded. Neither port should be allowed to "float".
- E. General Handling It is recommended that the MASW6010G chip be handled along the long side of the die with a sharp pair of bent tweezers. DO NOT touch the surface of the chip with fingers or tweezers.

Mounting

The MASW6010G is back-metalized with Pd/Ni/Au (100/1,000/30,000Å) metallization. It can be die -mounted using Au/Sn eutectic preforms or a thermally conductive epoxy. The package surface should be clean and flat before attachment.

Eutectic Die Attach:

- A. An 80/20 Au/Sn preform is recommended with a work surface temperature of approximately 255°C and a tool temperature of 265°C. When hot 90/10 nitrogen/hydrogen gas is applied, solder temperature should be approximately 290°C.
- B. DO NOT expose the MASW6010G to a temperature greater than 320°C for more than 20 seconds. No more than 3 seconds of scrubbing should be required for attachment.

Epoxy Die Attach:

- A. Electrically conductive epoxy must be used.
- B. Apply a minimum amount of epoxy and place the MASW6010G into position. A thin epoxy fillet should be visible around the perimeter of the die.
- C. Cure epoxy per manufacturer's recommended schedule.

Wire Bonding

- A. Ball or wedge bond with 1.0 mil diameter pure gold wire. Thermosonic wire bonding with a nominal stage temperature of 150°C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Ultrasonic energy and time should be adjusted to the minimum levels to achieve reliable wirebonds.
- B. Wirebonds should be started on the chip and terminated on the package.



GaAs SPDT Switch DC - 6.0 GHz

Rev. V6

M/A-COM Technology Solutions Inc. All rights reserved.

Information in this document is provided in connection with M/A-COM Technology Solutions Inc ("MACOM") products. These materials are provided by MACOM as a service to its customers and may be used for informational purposes only. Except as provided in MACOM's Terms and Conditions of Sale for such products or in any separate agreement related to this document, MACOM assumes no liability whatsoever. MACOM assumes no responsibility for errors or omissions in these materials. MACOM may make changes to specifications and product descriptions at any time, without notice. MACOM makes no commitment to update the information and shall have no responsibility whatsoever for conflicts or incompatibilities arising from future changes to its specifications and product descriptions. No license, express or implied, by estoppels or otherwise, to any intellectual property rights is granted by this document.

THESE MATERIALS ARE PROVIDED "AS IS" WITHOUT WARRANTY OF ANY KIND, EITHER EXPRESS OR IMPLIED, RELATING TO SALE AND/OR USE OF MACOM PRODUCTS INCLUDING LIABILITY OR WARRANTIES RELATING TO FITNESS FOR A PARTICULAR PURPOSE, CONSEQUENTIAL OR INCIDENTAL DAMAGES, MERCHANTABILITY, OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT. MACOM FURTHER DOES NOT WARRANT THE ACCURACY OR COMPLETENESS OF THE INFORMATION, TEXT, GRAPHICS OR OTHER ITEMS CONTAINED WITHIN THESE MATERIALS. MACOM SHALL NOT BE LIABLE FOR ANY SPECIAL, INDIRECT, INCIDENTAL, OR CONSEQUENTIAL DAMAGES, INCLUDING WITHOUT LIMITATION, LOST REVENUES OR LOST PROFITS, WHICH MAY RESULT FROM THE USE OF THESE MATERIALS.

MACOM products are not intended for use in medical, lifesaving or life sustaining applications. MACOM customers using or selling MACOM products for use in such applications do so at their own risk and agree to fully indemnify MACOM for any damages resulting from such improper use or sale.